L Number	Hits	Search Text	DB	Time stamp
4	1282	((118/712) or (118/713)).CCLS.	USPAT;	2003/06/02 00:46
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
47	40	"0040500"	IBM_TDB	0000/00/00 04 45
47	13	"6016562"	USPAT	2003/06/02 01:15
48 448	1 7	("6031607").PN. 356/\$.ccls. and (adjustable near3 intens\$4) and	USPAT	2003/06/02 01:16 2003/06/02 01:42
440	·	semiconductor and thickness	USPAT; US-PGPUB;	2003/06/02 01.42
		Serificonductor and trickness	EPO; JPO;	
		<i>V</i>	DERWENT;	
			IBM_TDB	
449	25	356/\$.ccls. and (adjustable near3 illuminat\$4) and	USPAT;	2003/06/02 01:37
		semiconductor and thickness	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
450	73	356/\$.ccls. and (variable near3 intens\$4) and	USPAT;	2003/06/02 01:42
		semiconductor and thickness	US-PGPUB;	
i i			EPO; JPO;	
[DERWENT;	
	915231	@pd>20020514	IBM_TDB USPAT;	2002/12/16 02:51
	310201	@pu-20020014 	US-PGPUB;	2002/12/10 02.31
			EPO; JPO;	
			DERWENT;	
}			IBM TDB	
-	0	118/\$.ccls. and ((illuminat\$ near5 visual) same	USPAT;	2002/12/16 02:53
		(semiconductor))	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1	00	@ nd> 00000544 and (440)50 and an 440,50 and	IBM_TDB	00004040
-	90	@pd>20020514 and (118/50.ccls. or 118/52.ccls. or 118/50.1.ccls. or 118/56.ccls.)	USPAT;	2002/12/16 02:54
		110/30.1.Ccis. 01 110/30.ccis.)	US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	150	@pd>20020514 and (118/320.ccls. or 118/326.ccls. or	USPAT;	2002/12/16 04:08
		118/712.ccls. or 118/713.ccls. or 118/501.ccls. or	US-PGPUB;	
		118/500.ccls.)	EPO; JPO;	
			DERWENT;	
	207	G., 15 00000544	IBM_TDB	
-	307	@pd>20020514 and (222/113.ccls. or 362/231.ccls. or	USPAT;	2002/12/16 11:24
		355/53.ccls. or 355/70.ccls. or 396/611.ccls.)	US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM_TDB	
<u>-</u>	157	@pd>20020514 and (156/379.ccls. or 427/8.ccls. or	USPAT;	2002/12/16 11:24
]		427/9.ccls. or 427/10.ccls. or 427/240.ccls. or 427/425.ccls.)	US-PGPUB;	
		,	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	259	@pd>20020514 and (362/145.ccls. or 362/147.ccls. or	USPAT;	2002/12/16 11:25
		362/149.ccls. or 362/154.ccls. or 362/155.ccls. or	US-PGPUB;	
]		362/800.ccls. or 362/803.ccls. or 362/458.ccls. or 362/253.ccls.)	EPO; JPO;	
		- 002/200.0013.)	DERWENT; IBM_TDB	
_	14	118/\$.ccls. and ((visual near3 inspection) same (chuck or	USPAT;	2002/12/16 02:54
]	• • •	holder or table))	US-PGPUB;	2302/12/10 02.04
			EPO; JPO;	
			DERWENT;	
<u> </u>			IBM_TDB	

Skockur

-	9	118/\$.ccls. and ((visual near3 inspection) same (semiconductor))	USPAT; US-PGPUB;	2002/12/16 02:54
		"	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	80	118/\$.ccls. and ((illuminat\$) same (semiconductor))	USPAT;	2002/12/16 02:54
1	[US-PGPUB;	
		,	EPO; JPO;	
			DERWENT;]
	169	119/\$ cols, and //illuminat\$) come (chamber)	IBM_TDB USPAT;	2002/12/16 02:54
-	109	118/\$.ccls. and ((illuminat\$) same (chamber))	US-PGPUB;	2002/12/16 02.54
İ			EPO; JPO;	
			DERWENT;	
	1		IBM_TDB]
	558	(427/\$.ccls. or 118/\$.ccls.) and (LED or "light emitting diode"	USPAT;	2002/12/16 02:55
		or "light emitting diodes") and controller	US-PGPUB;	
	1	· · · · · · · · · · · · · · · · · · ·	EPO; JPO;	
			DERWENT;	
1	1		IBM_TDB	
-	1	"5843527".PN.	USPAT	2002/12/16 03:05
] -	171	(427/\$.ccls. or 118/\$.ccls.) and (LED or "light emitting diode"	USPAT;	2002/12/16 03:20
1	1	or "light emitting diodes") and (controller same (input or	US-PGPUB;	
		output))	EPO; JPO;	
1			DERWENT;	
1	1	6122042.pn.	IBM_TDB	2002/12/16 03:06
1.	1 1	6122042.pn. 6122042.pn. and (coat or coating)	USPAT USPAT	2002/12/16 03:06 2002/12/16 03:07
1-	, i	(427/\$.ccls. or 118/\$.ccls.) and (*diode*) and (thickness) and	USPAT:	2002/12/16 03:07
1		(photoresist)	US-PGPUB;	2002/12/10 00.21
1		\(\text{\tint{\text{\tint{\text{\tin}\text{\text{\text{\text{\text{\text{\text{\text{\text{\ti}\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\tin}\tint{\texi}\tinz}{\text{\text{\text{\text{\text{\tin}}\tint{\text{\text{\texi{\text{\texit{\text{\text{\texi}\text{\texi}\tint{\text{\texit{\texi}\tinz}\tint{\text{\ti}\tint{\tint{\tin}}\tint{\tin}}}}}}}}}	EPO; JPO;	
		`	DERWENT;	
			IBM_TDB	
-	0	(427/\$.ccls. or 118/\$.ccls.) and (*diode*) and (thickness)	USPAT;	2002/12/16 03:21
			US-PGPUB;	
			EPO; JPO;	
] 1			DERWENT;	
_	303	(427/\$.ccls. or 118/\$.ccls.) and (photodiode) and (thickness)	IBM_TDB USPAT;	2002/12/16 03:31
1 -	303	(¬21/ψ. ccis. or 110/ψ. ccis.) and (photodiode) and (thickness)	US-PGPUB;	2002/12/10 03.31
			EPO; JPO;	
		•	DERWENT;	
			IBM_TDB	
-	44	(427/\$.ccls. or 118/\$.ccls.) and (photodiode) and (thickness)	USPAT;	2002/12/16 03:21
		and photoresist	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		(440/0 ppln) and (nhate 32 de) and (112 de)	IBM_TDB	00004040
-	31	(118/\$.ccls.) and (photodiode) and (thickness) and controller	USPAT;	2002/12/16 03:37
			US-PGPUB;]
			EPO; JPO; DERWENT;	
1			IBM_TDB	
-	7	"5985357"	USPAT	2002/12/16 04:16
-	68	process and chamber and anti-reflective and 118/\$.ccls.	USPAT;	2002/12/16 11:27
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
] -	4620	(118/320.ccls. or 118/326.ccls. or 118/712.ccls. or	USPAT;	2002/12/16 04:08
ļ		118/713.ccls. or 118/501.ccls. or 118/500.ccls.)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1	4713140.pn.	IBM_TDB USPAT	2002/12/16 10:22
لــــــا	<u> </u>	[1/ 10 1 10.pm.	1 201 71	2002112110 10.22

-	1	4696209.pn.	USPAT	2002/12/16 11:19
-	1	4227347.pn.	USPAT	2002/12/16 11:19
-	3036	1 3	USPAT;	2002/12/16 11:24
1		355/70.ccls. or 396/611.ccls.)	US-PGPUB;	
İ			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	3255	156/379.ccls. or 427/8.ccls. or 427/9.ccls. or 427/10.ccls. or	USPAT;	2002/12/16 11:25
		427/240.ccls. or 427/425.ccls.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	3803	(362/145.ccls. or 362/147.ccls. or 362/149.ccls. or	USPAT;	2002/12/16 11:54
]	362/154.ccls. or 362/155.ccls. or 362/800.ccls. or	US-PGPUB;	
		362/803.ccls. or 362/458.ccls. or 362/253.ccls.)	EPO; JPO;	
	· ·		DERWENT;	
			IBM_TDB	
-	366814	process and chamber and non-reflective and 118/\$.ccls.	USPAT;	2002/12/16 11:42
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	10	process and chamber and non-reflective and 118/\$.ccls.	USPAT;	2002/12/16 11:43
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	4	process and chamber and nonreflective and 118/\$.ccls.	USPAT;	2002/12/16 11:44
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
•			IBM_TDB	
-	160	118/677	USPAT;	2003/06/02 01:14
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	4044	400/40	IBM_TDB	
-	1214	438/16	USPAT;	2003/05/31 22:19
			US-PGPUB;	
	İ		EPO; JPO;	
			DERWENT;	
	444	420/40 4 4 4 4 4	IBM_TDB	0000/00/04 00 57
-	114	438/16 and reflectivity	USPAT;	2003/06/01 22:57
,			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	46	439/46 and /illumination many intensity	IBM_TDB	2002/00/04 22 22
. -	16	438/16 and (illumination near3 intensity)	USPAT;	2003/06/01 23:38
1			US-PGPUB;	
			EPO; JPO;	
		·	DERWENT;	
	ا م	(449/742 pole) and (illumination many) interests)	IBM_TDB	0000/00/04 00 07
1-	1	(118/713.ccls.) and (illumination near3 intensity)	USPAT;	2003/06/01 23:37
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		(440/740 and) and (illumination of a second of the condition of the condi	IBM_TDB	0000100104 00 00
-	4	(118/712.ccls.) and (illumination near3 intensity)	USPAT;	2003/06/01 23:37
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	·
L	L		IBM_TDB	L

-	20	438/16 and (illuminat\$4 near3 intens\$4)	USPAT;	2003/06/01 23:48
			US-PGPUB;	
	1		EPO; JPO;	
		, in the second	DERWENT;	
			IBM_TDB	
-	1910	356/\$.ccls. and (illuminat\$4 near3 intens\$4)	USPAT;	2003/06/01 23:48
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	559		USPAT;	2003/06/01 23:50
		semiconductor	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	281	356/\$.ccls. and (illuminat\$4 near3 intens\$4) and	USPAT;	2003/06/02 01:34
		semiconductor and thickness	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			I IBM TDB	